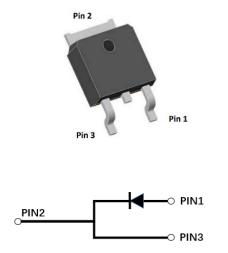


V _{RRM}	1200V
IF (135°C)	7A
Qc	27nC



Features

- Positive temperature coefficient
- Temperature-independent switching
- Maximum working temperature at 175 °C
- Unipolar devices and zero reverse recovery current
- Zero forward recovery current
- Essentially no switching losses
- Reduction of heat sink requirements
- AEC-Q101 qualified
- High-frequency operation
- Reduction of EMI

Typical Applications

Typical applications are in power factor correction(PFC), solar inverter, uninterruptible power supply, motor drives, photovoltaic inverter, electric car and charger.

Mechanical Data

- Package: TO-252
- Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant, halogen-free
- Terminals: Tin plated leads
- Polarity: As marked

■Maximum Ratings (T_c **=**25°C Unless otherwise specified)

PARAMTETER	SYMBOL	UNIT	VALUE
Device marking code			D112005DG1
Reverse voltage (Repetitive peak) @ T _j =25°C	V _{RRM}	V	1200
Reverse voltage (Surge peak) @ T _j =25°C	V _{RSM}	V	1200
Reverse voltage (DC) @ T _j =25°C	V _{DC}	V	1200
Continuous forward current @ T _c =25°C		A	14.8
Continuous forward current @ T _c =135°C	IF		7
Continuous forward current @ T _c =153°C			5
Non-repetitive peak forward surge current @ T_c =25°C, tp=10ms, Half Sine Wave	I _{FSM}	А	50
Power Dissipation@ T _c =25°C	_	w	71
Power Dissipation@ T _c =110°C	P _{TOT}		31
i²t Value@ Tc=25°C ,tp=10ms	∫ i²dt	A ² S	12.5
Operating junction and Storage temperature range	T _j ,T _{stg}	°C	-55 to +175



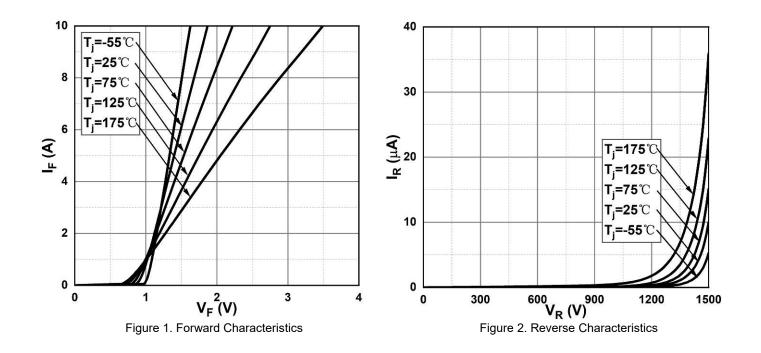
Electrical Characteristics

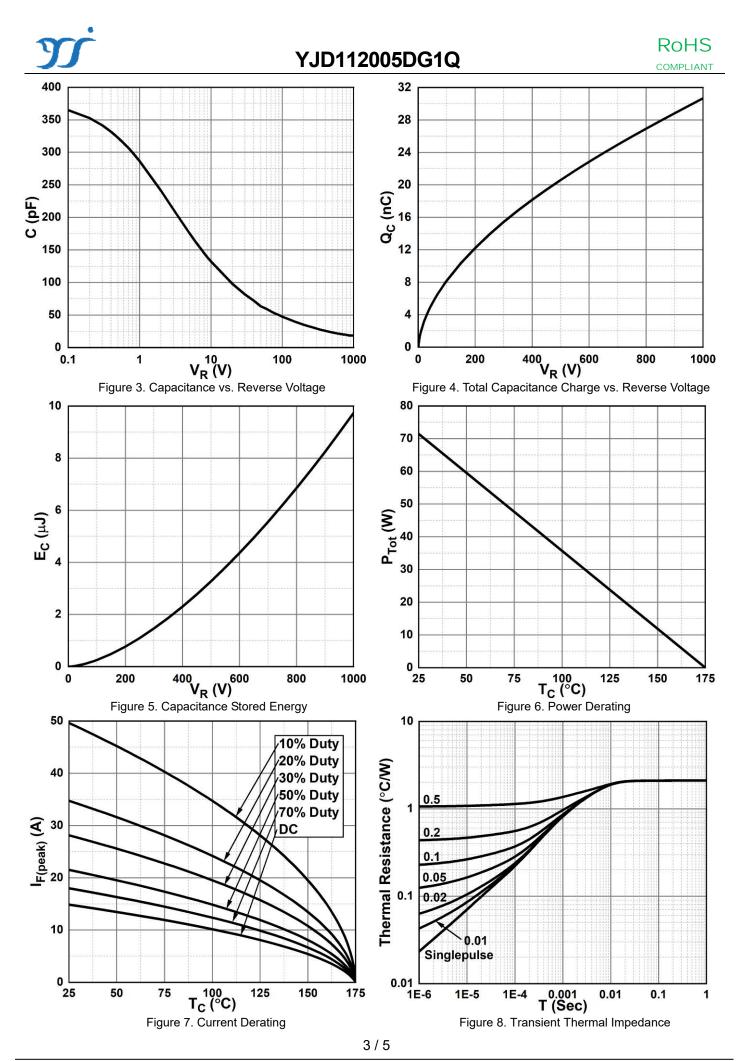
PARAMTETER	SYMBOL	UNIT	TEST CONDITIONS	Тур.	Max.
Forward voltage dran	V _F	V	I _F =5A, T _j =25°C	1.41	1.6
Forward voltage drop	VF	v	I _F =5A, T _j =175°C	2.1	-
		μΑ	V _R =1200V, T _j =25°C	0.5	16
Reverse leakage current	I _R		V _R =1200V, T _j =175°C	8	-
Total capacitive charge	Qc	nC	V_R =800V, T _j =25°C , Q_C = \int_0^{VR} C(V)dV	27	-
			V _R =0V, f=1MHZ	377	-
Total capacitance C	pF	V _R =400V, f=1MHZ	25	-	
		V _R =800V, f=1MHZ	19	-	
Capacitance Stored Energy	Ec	μJ	V _R =800V	6.8	-

Thermal Characteristics $(T_a=25^{\circ}C \text{ Unless otherwise specified})$

PARAMETER	SYMBOL	UNIT	VALUE
Thermal resistance	$R_{_{ ext{ hetaJ-C}}}$	°C /W	2.1

■Typical Characteristics

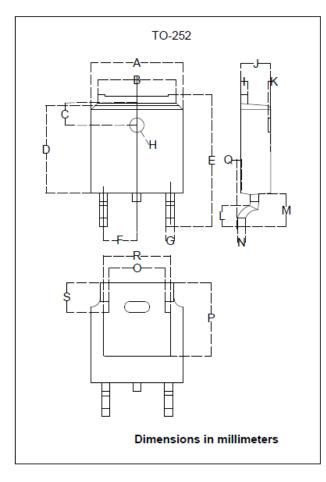




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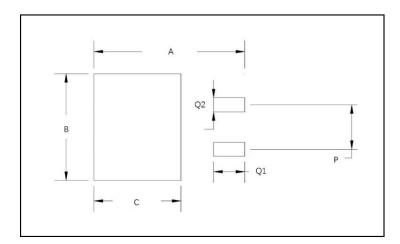


Outline Dimensions



	TO-252			
Dim	Min	Max		
А	6.500	6.700		
В	5.100	5.460		
С	1.400	1.800		
D	6.000	6.200		
E	10.000	10.400		
F	2.166	2.366		
G	0.660	0.860		
Н	Φ1.050	Ф1.350		
I	0.460	0.580		
J	2.200	2.400		
К	0	0.300		
L	0.890	2.290		
М	2.730	3.080		
Ν	0.430	0.580		
0	4.20	4.95		
Р	5.15	5.45		
Q	0	0.2		
R	4.50	5.10		
S	1.60	2.40		

Suggested Pad Layout



Dim	Millimeters
А	11.4
В	6.74
С	6.23
Р	4.56
Q1	2.28
Q2	1.52

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Disclaimer

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